TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

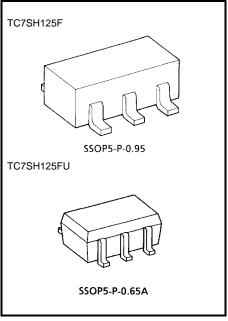
TC7SH125F,TC7SH125FU

Bus Buffer

Features

High speed: t_{pd} = 3.8 ns (typ.) at $V_{\rm CC}$ = 5 V Low power dissipation: $I_{\rm CC}$ = 2 μ A (max) at Ta = 25°C High noise immunity: $V_{\rm NIH}$ = $V_{\rm NIL}$ = 28% $V_{\rm CC}$ (min) 5.5V tolerant input.

Wide operating voltage range: $V_{\rm CC}$ (opr) = 2~5.5 V



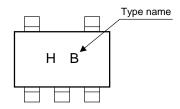
Weight

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

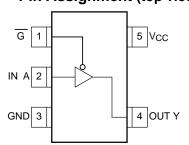
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	٧
DC output voltage	Vout	-0.5~V _{CC} + 0.5	٧
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	P _D	200	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10 s)	TL	260	°C

Marking



Pin Assignment (top view)





Logic Diagram



Truth Table

G	Α	Υ
Н	Х	Z
L	L	L
L	Н	Н

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
		0~ V _{CC}		
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 V \pm 0.3 V)	ns/V	
input rise and rail time	ui/uv	0~20 (V_{CC} = 5 $V \pm 0.5 V$)		

DC Electrical Characteristics

Characteristics Symbol Test Circuit			Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
		rest Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
High-level input voltage VIH —		_		2.0	1.5	_	_	1.5	_	V	
				3.0~5.5	V _{CC} × 0.7	_	_	V _{CC} × 0.7	_		
Low-level input					2.0	_	_	0.5	_	0.5	
voltage	V _{IL}	_		_		_	_	V _{CC} × 0.3	_	V _{CC} × 0.3	V
			$V_{IN} = V_{IH}$	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	V
		_			3.0	2.9	3.0	_	2.9	_	
High-level output voltage	High-level VOH				4.5	4.4	4.5	_	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_		
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	_		3.80	_	
Low-level output voltage		V _{IN} = V _{IH}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	V	
				3.0	_	0	0.1	_	0.1		
	_			4.5	_	0	0.1	_	0.1		
			$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44		
				$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36	_	0.44	1
Input leakage current	I _{IN}	_	V _{IN} = 5.5 V or GND		0~5.5	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	Icc	_	V _{IN} = V _{CC} or GND		5.5	_	_	2.0	_	20.0	μА

TC7SH125F/FU



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics Symbol	Circuit		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Offic	
				3.3 ± 0.3	15	_	5.6	8.0	1.0	9.5	
Propagation delay	t _{pLH}				50	_	8.1	11.5	1.0	13.0	
time t _{pHL}	_		50.05	15	_	3.8	5.5	1.0	6.5	ns	
				5.0 ± 0.5	50	_	5.3	7.5	1.0	8.5	
	^t pZL			3.3 ± 0.3	15	_	5.4	8.0	1.0	9.5	- ns
enable time					50	_	7.9	11.5	1.0	13.0	
				5.0 ± 0.5	15	_	3.6	5.1	1.0	6.0	
				5.0 ± 0.5	50	_	5.1	7.1	1.0	8.0	
disable time	t _{pLZ}	_		3.3 ± 0.3	50	_	9.5	13.2	1.0	15.0	ns
	t _{pHZ}			5.0 ± 0.5	50	_	6.1	8.8	1.0	10.0	115
Input capacitance	C _{IN}	_		_		_	4	10	_	10	pF
Output capacitance	C _{OUT}	_				_	6	_	_	_	pF
Power dissipation capacitance	C _{PD}	_			(Note)	_	14	_	_	_	pF

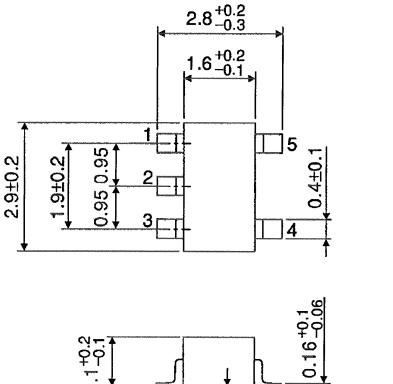
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

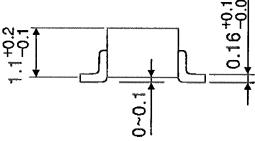
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Package Dimensions

SSOP5-P-0.95 Unit: mm

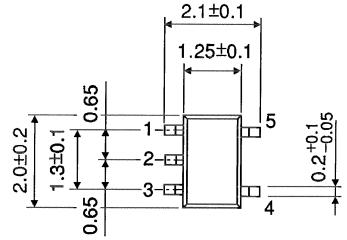


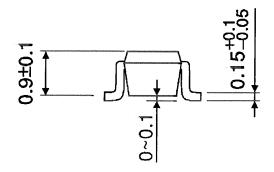


Weight: 0.016 g (typ.)

Package Dimensions

SSOP5-P-0.65A Unit: mm





Weight: 0.006 g (typ.)

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